

**UT3400-H**

Preliminary

Power MOSFET

5.8A, 30V N-CHANNEL ENHANCEMENT MODE POWER MOSFET

DESCRIPTION

The UTC **UT3400-H** is an N-ch enhancement MOSFET providing the customers with perfect $R_{DS(ON)}$ and low gate charge. This device can be operated with 2.5V low gate voltage.

The UTC **UT3400-H** is optimized for applications, such as a load switch or in PWM.

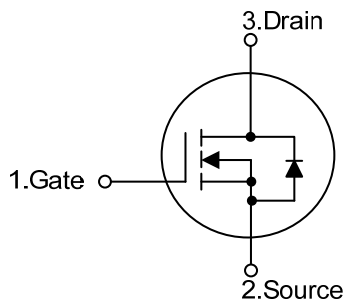
FEATURES

* $R_{DS(ON)} \leq 32m\Omega$ @ $V_{GS}=10V$, $I_D=5.8A$

$R_{DS(ON)} \leq 35m\Omega$ @ $V_{GS}=4.5V$, $I_D=5A$

$R_{DS(ON)} \leq 52m\Omega$ @ $V_{GS}=2.5V$, $I_D=4A$

SYMBOL



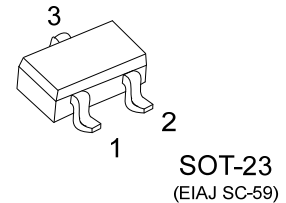
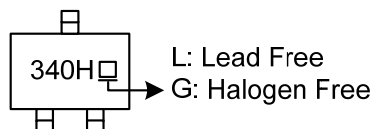
ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
UT3400L-AE3-R	UT3400G-AE3-R	SOT-23	G	S	D	Tape Reel

Note: Pin Assignment: G: Gate S: Source D: Drain

UT3400G-AE3-R 		(1) R: Tape Reel (2) AE3: SOT-23 (3) G: Halogen Free and Lead Free, L: Lead Free
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MARKING



■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	± 12	V
Continuous Drain Current	I_D	5.3	A
Pulsed Drain Current (Note 2)	I_{DM}	21.2	A
Power Dissipation	P_D	1.56	W
Junction Temperature	T_J	+150	°C
Storage Temperature	T_{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Pulse width limited by $T_{J(MAX)}$

3. Pulse width $\leq 300\mu s$, duty cycle $\leq 0.5\%$

4. L = 50mH, $I_{AS} = 2A$, $V_{DD} = 50V$, $R_G = 25\Omega$, Starting $T_J = 25^\circ C$

5. $I_{SD} \leq 7A$, $di/dt \leq 200A/\mu s$, $V_{DD} \leq BV_{DSS}$, Starting $T_J = 25^\circ C$

■ THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient (Note)	θ_{JA}	80	°C/W

Note: Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

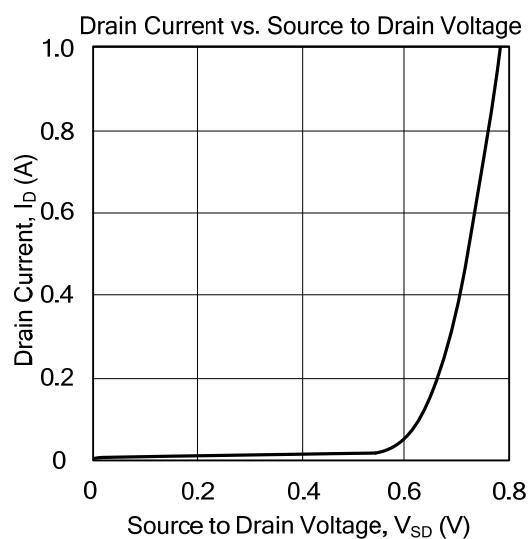
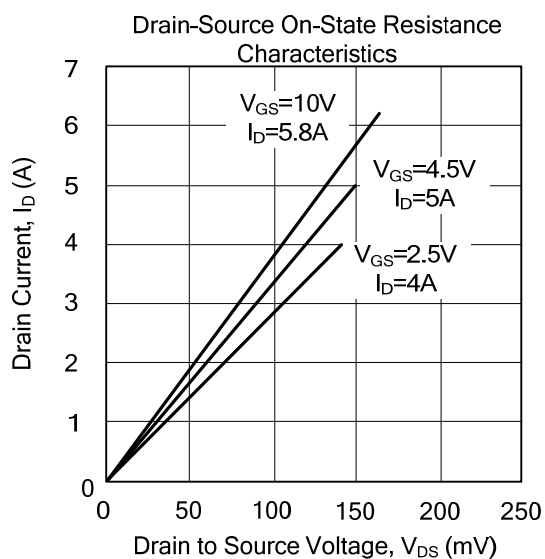
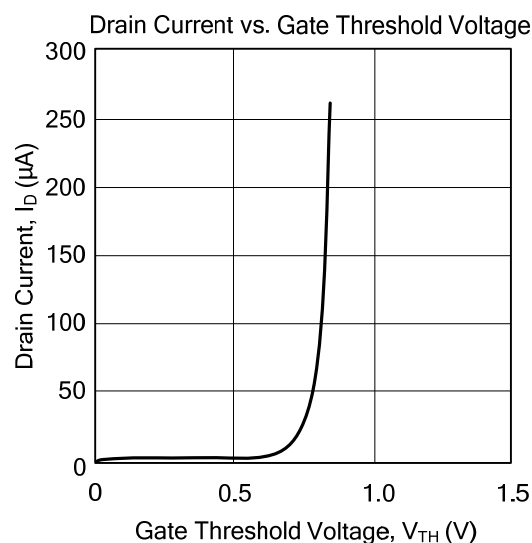
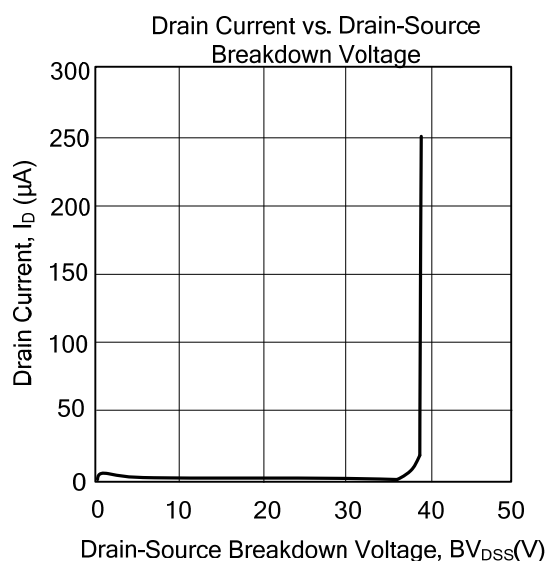
■ ELECTRICAL CHARACTERISTICS ($T_J=25^\circ C$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250μA	30			V
Drain-Source Leakage Current	I _{DSS}	V _{DS} =24V, V _{GS} =0V			1	μA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±12V, V _{DS} =0V			100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	V _{DS} =V _{GS} , I _D =250μA	0.4	0.75	0.9	V
On-State Drain Current	I _{D(ON)}	V _{DS} =5V, V _{GS} =4.5V	30			A
Drain to Source On-state Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =5.8A		28	32	mΩ
		V _{GS} =4.5V, I _D =5A		30	35	mΩ
		V _{GS} =2.5V, I _D =4 A		36	52	mΩ
DYNAMIC PARAMETERS						
Input Capacitance	C _{ISS}	V _{DS} =15V, V _{GS} =0V, f =1MHz		695		pF
Output Capacitance	C _{OSS}			45		pF
Reverse Transfer Capacitance	C _{RSS}			36		pF
Gate Resistance	R _G	V _{GS} =0V, V _{DS} =0V, f =1MHz		1.5	3.0	Ω
SWITCHING PARAMETERS						
Total Gate Charge	Q _G	V _{GS} =4.5V, V _{DS} =10V, I _D =4A		8.4	12	nC
Gate Source Charge	Q _{GS}			1	2	nC
Gate Drain Charge	Q _{GD}			2.2	4	nC
Turn-ON Delay Time	t _{D(ON)}	V _{GS} =4.5V, V _{DS} =10V, I _D =1A R _G =25Ω		4.5	9	ns
Turn-ON Rise Time	t _R			13	25	ns
Turn-OFF Delay Time	t _{D(OFF)}			27	51	ns
Turn-OFF Fall-Time	t _F			8.3	16	ns
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS						
Diode Continuous Forward Current (Note 1)	I _S				5.3	A
Drain-Source Diode Forward Voltage	V _{SD}	I _S =1A, V _{GS} =0V			1	V

Notes: 1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Pulse width $\leq 300\mu s$, duty cycle $\leq 0.5\%$

■ TYPICAL CHARACTERISTICS



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